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## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

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<b>M</b> e re	Patent Application of	)
Kazı	iya KAMON	) Group Art Unit: 1756
Appl	lication No.: 09/320,946	) ) Examiner: S. Mohamedulla )
Filed	l: May 26, 1999	)
For:	PHOTOMASK, FABRICATION METHOD OF PHOTOMASK, AND FABRICATION METHOD OF SEMICONDUCTOR INTEGRATED CIRCUIT	) ) ) ) ) )
	PETITION FOR E	EXTENSION OF TIME
	stant Commissioner for Patents hington, D.C. 20231	
Sir:		,
	The following extension of time is requested	ted to respond to Office Action dated December 5,
<u>2000</u>	and Advisory Action dated March 14, 200	<u>)1</u> :
	one month to April 5, 2001	; the extension fee is:
	[ ] \$55.00 (215) [X] \$110.00 (115	5).
	[ ] The shortened statutory period has be	been reset by an Advisory Action dated
	[X] An extension fee in the amount of \$_	110.00 is enclosed.
	[ ] Charge \$to Deposit Acc	count No. 02-4800.
	The Commissioner is hereby authorized to	o charge any appropriate fees under 37 C.F.R.
§§ 1	.16, 1.17 and 1.21 that may be required by	this paper, and to credit any overpayment, to
Depo	osit Account No. 02-4800. This paper is su	ıbmitted in duplicate.
		Respectfully submitted.

By:

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110.00 GP

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Date: April 4, 2001

(11/00)